CXA1610M

RF Amplifier for CD Players

Description

The CXA1610M is an IC developed for compact disc players. The IC incorporates an APC circuit, and amplifiers for 3-spot optical pick-up output, focus error, and tracking error. (Corresponds to voltage-converted optical pick-up outputs only.)

Features

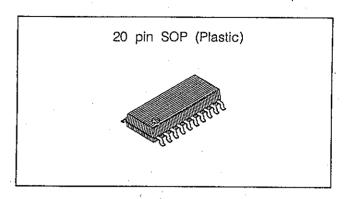
- Low power consumption (70mW at ±5V)
- Built-in APC (automatic power control) circuit
- Enables both dual ±5V power supply, and single +5V power supply

Application

Compact disc players

Structure

Bipolar silicon monolithic IC



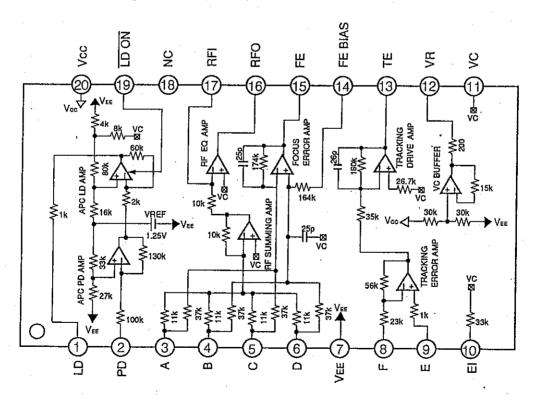
Absolute Maximum Ratings

- Supply voltage
 Operating temperature
 Storage temperature
 Allowable power dissipation
 Vc
 Topr -20 to +75 °C
 Tstg -65 to +150 °C
 MW

Operating Conditions

• Supply voltage Vcc-VEE 3.6 to 11.0 V

Block Diagram and Pin Configuration (Top View)



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Pin Description

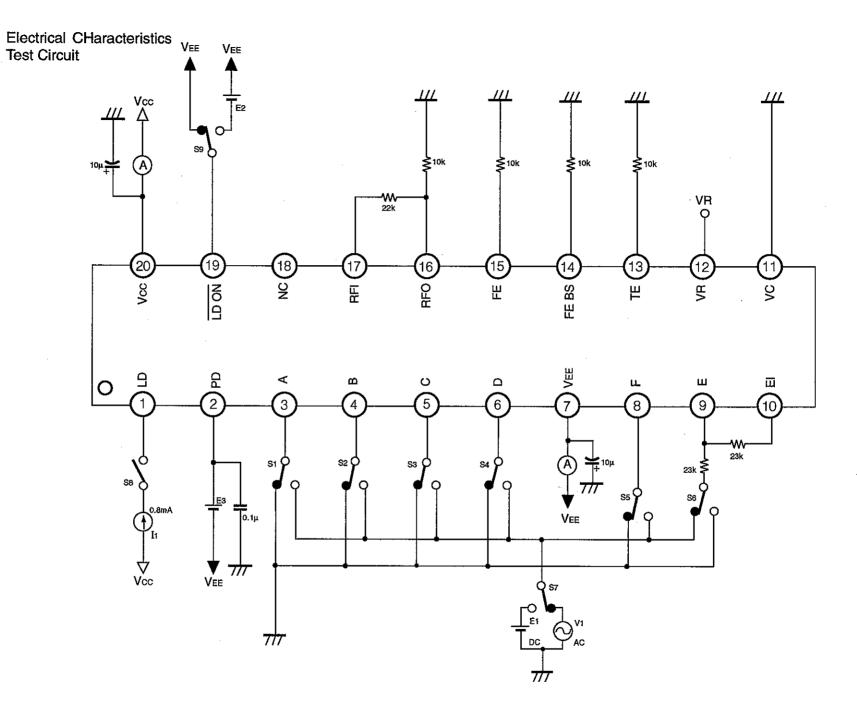
Pin No	Symbol	I/O	Equivalent circuit	Description
1	LD	0	① 1k Vcc VEE	APC amplifier output
2	PD		2 100k VEE VEE VEE	APC amplifier input
3 4 5 6 14	A B C D FE BIAS	 	Vcc Vcc Vcc Vcc Vcc Vcc A 3 11k 164k 174k 174k 164k 174k 174k 164k 174k 174k 164k 174k 174k 174k 164k 174k 174k 174k 174k 174k 174k 174k 17	Pins 3, 4, 5 and 6 are inputs for the RF amplifier and FE amplifier. Pin 14 is for focus bias adjustment.
7	VEE	1		VEE
8 9	F E		F 8 W VEE	Tracking error amplifier input.

Pin No	Symbol	I/O	Equivalent circuit	Description
10	El		10 → W ⊠VC	33kΩ resistance is between VC and this pin. Use by connecting with TE adjustment volume.
11	VC	l	① ■ ■ vc	Center voltage input for VC Connect to GND when using dual ±5 V power supply; connect to VR pin when using single + 5V power supply.
12	VR	0	Vcc 200	DC voltage output for (Vcc+VEE)/2
13	TE	0	160k W 26p	Tracking error amplifier output. Outputs F-E signals.

Pin No	Symbol	1/0	Equivalent circuit	Description
15	FE	0	174k VCC 15 25p 174k	Focus error amplifier output
16	RFO	0	VCC VEE	RF amplifier output
17	RFI		10k W 100µ 4.1k VEE	RF amplifier inversed input. Gain of RF amplifier is determined by the resistance connected between this pin and RFO pin.
18	NC			No connected
19	LD ON		Vcc 40k	Switch for APC amplifier ON/OFF ON at GND, OFF at Vcc
20	Vcc			Vcc

	Test No. Test item		Symbol	5	W	cor	nditi	ion	s*	Bias	condi	tions	Test	Description of I/O	waveform	Min.	T		I I a fa
IN.). 			1	2 3	4 5	6	7 8	3 9	E1	E2	E3	pin	test metho	od	I WIII.	Тур.	Max.	Unit
		Current consumption	lcc	Ш									20				7.0	11.0	mΑ
2	_		IEE			\perp							7			-11.0	-7.0		mΑ
3	_ ji	Offset voltage 1	V16-1				1	\perp					16	Input GND		-20.0		20.0	m۷
5	⊢ કે	Voltage gain		+ +	20			_ .	\perp	·	<u></u>		16	Input 1 kHz, 150 mVp-p		15.1	18.1	21.1	dΒ
6	┦ "	L Max. output amplitude 11	V16-3	1			+	0	_	+400mV			16			1.3	_	_	V
7	-	Max. output amplitude L	V16-4	P		잋		의		-400mV			16					-0.3	V
8	4	Offset voltage	V15-1	Ц	$\perp \downarrow$	\perp	Ц		\perp	,, .			15	Input GND	Output DC test	-30.0	0	30.0	m۷
9	<u>ا</u> نْ	Voltage gain 1	V15-2		0			_					15	Input 1 kHz, 300 mVp-p	Output AC test	16.5	19.5	22.5	dВ
10	ન દ્ર	Voltage gain 2	V15-3	<u>L</u>				╧					15	Input 1 kHz, 300 mVp-p	Output AC test	16.5	19.5	22.5	dB
1	\dashv \blacksquare	II TORREGO GARTI AMOTOTION	V15-4		\perp	╧				-			1	V15-4 = V15-2 - V15-3		-3.0	0	3.0	dΒ
5 12	4 -	- Iviax. output amplitude L	V15-5	0						+300mV			15		Output DC test	-		-1.9	٧
1 13	+	Max. output amplitude"H"	V15-6					2		+300mV			15		Output DC test	1.9			V
14		Offset voltage 1	V 13-1		Ш	╧					•		13	Input GND	Output DC test	-30	0	30	m۷
15	ةِ لَـٰ	Voltage gain 1	V13-2	Ш	$\perp \downarrow$	þ	Ш					,	13	Input 1 kHz, 100 mVp-p	Output AC test	17.9	20.9	23.9	dB
16	amplifier	Voltage gain 2	V13-3	Ш			þ						13	Input 1 kHz, 100 mVp-p	Output AC test	17.9	20.9	23.9	dΒ
17	⊢ш	- process sant amorpho	V13-4		Ш								13			-3.0	0	3.0	dB
18	~	Max. output amplitude"H"	V13-5			þ		2		+240mVpc			13		Output DC test	1.9			٧
19	-	Max. output amplitude"L"	V13-6				þ	2	Ш	+240mVpc			13		Output DC test			-1.9	٧
20	4	Output voltage 1	V1-1		Ш	\perp			O		0.5V	+69mV	1		Output DC test		-1.6	-0.3	٧
21] _	Output voltage 2	V1-2						þ		0.5V	+123mV	1		Output DC test	-1.5	-0.2	1.1	V
22	⊣ ∢	Output voltage 3	V1-3					Ĺ	þ		0.5V	+177mV	1		Output DC test	0.6	1.9		٧
23	⊣	Output voltage 4	V1-4						þ		4.5V	+0mV	1	·	Output DC test	2.1	2.4		٧
24	i	Output voltage 5	V1-5				Ц	c	p		0.5V		1	· · · · · · · · · · · · · · · · · · ·	Output DC test			0	٧
25	Center	Output voltage 1	V12-1										12			-100		+100	mV

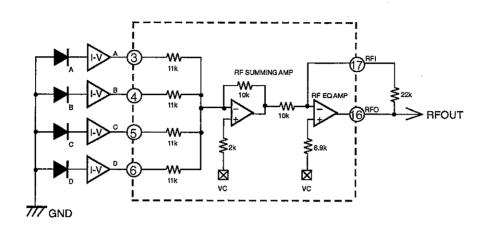
*O represents ON condition.



Description of Functions

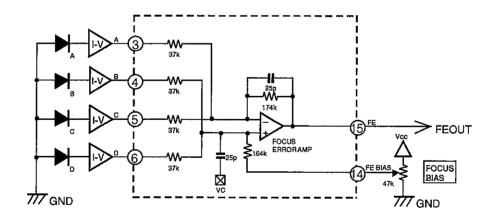
RF amplifier

Signal currents from photodiodes A, B, C, and D are I-V converted and input to Pins 3, 4, 5, and 6. These signals are added to by the RF summing amplifier, equalized by the RF equalizing amplifier, and then output to Pin 16. When equalizing RF signals, insert an equalizing circuit between Pins 16 to 17.



Focus error amplifier

The operation of (B+D)-(A+C) is performed and output to Pin 15. Pin 14 is for the bias adjustment of the focus error signals.

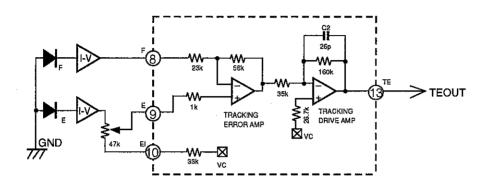


Tracking error amplifier

The signal current of photodiode F is I-V converted and applied to Pin 8. The signal current of photodiode E is I-V converted, and then gain-adjusted by the volume, and input to Pin 9. These signals are operated and amplified by the tracking error amplifier and the tracking drive amplifier to become (F-E) signals, and are output to Pin 13.

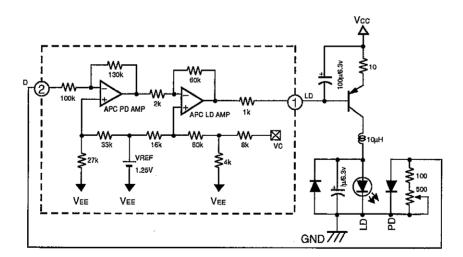
Also, because the 33 k Ω resistor between Pin 10 and VC is the IC's internal resistance, the absolute error is approximately $\pm 20\%$, and temperature characteristic is about -1×10^{-3} °C.

Caution is necessary when using this resistor under harsh temperature conditions.



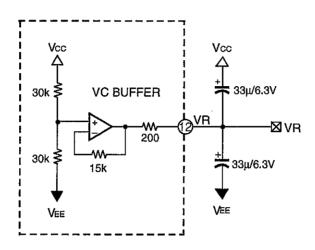
APC circuit

When the laser diode is under constant current drive, optical output will have large, negative temperature characteristics. Thus, in order to stabilize the optical output, a monitor photodiode must be used to control the current. The figure below is the APC circuit. APC is turned ON by grounding LD ON pin; OFF by connecting to Vcc.



Center voltage generation circuit

Center voltage is supplied when the CXA1610M is used on single power supply. Maximum current is approximately ± 3 mA. Output impedance is approximately 200Ω .



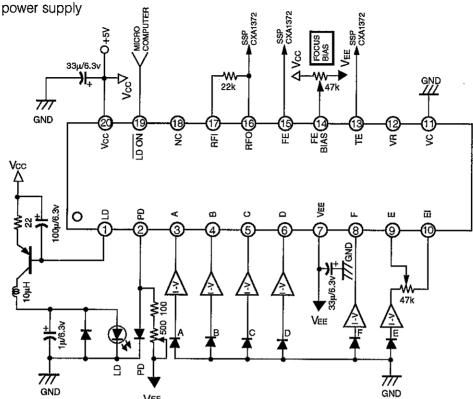
Notes on Operation

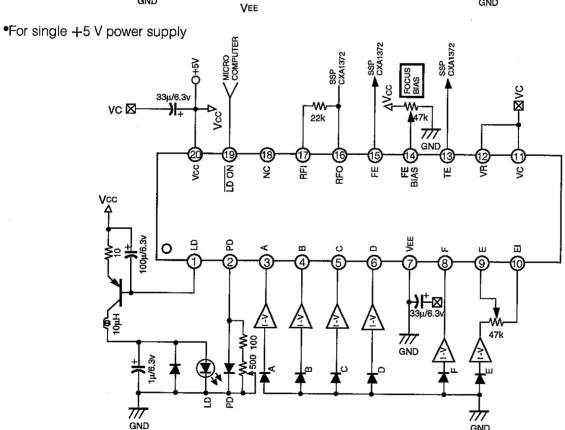
1.Power supply

The CXA1610M can be used on both \pm dual power supply and single power supply. Connections of power supplies on each case are shown in the following table.

·	Vcc	VEE	VR	VC
±Dual power supply	+Power supply	-Power supply	OPEN	GND
Single power supply	Power supply	GND	VC	VR

Application Circuit
•For dual ±5 V power supply



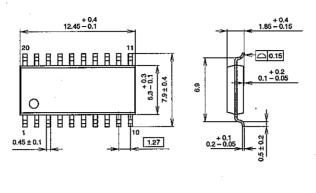


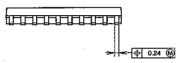
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Package Outline

Unit: mm

20PIN SOP (PLASTIC)



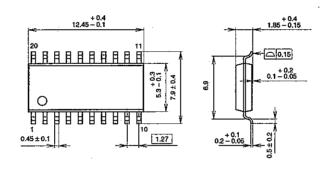


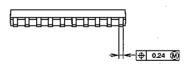
PACKAGE STRUCTURE

SONY CODE	SOP-20P-L01
EIAJ CODE	SOP020-P-0300
JEDEC CODE	

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER ALLOY
PACKAGE MASS	0.3g

20PIN SOP (PLASTIC)





PACKAGE STRUCTURE

SONY CODE	SOP-20P-I.01
EIAJ CODE	SOP020-P-0300
JEDEC CODE	

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER ALLOY
PACKAGE MASS	0.3g

LEAD PLATING SPECIFICATIONS

ITEM	SPEC.
LEAD MATERIAL	COPPER ALLOY
SOLDER COMPOSITION	Sn-Bi Bl:1-4wt%
PLATING THICKNESS	5-18µm